JFET Chopper
P-Channel - Depletion

## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Drain-Gate Voltage | $\mathrm{V}_{\mathrm{DG}}$ | 25 | V |
| Reverse Gate-Source Voltage | $\mathrm{V}_{\mathrm{GS}}(\mathrm{r})$ | -25 | V |

## MMBFJ175LT1

Motorola Preferred Device


CASE 318-08, STYLE 10 SOT-23 (TO-236AB)

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Total Device Dissipation FR-5 Board <br> $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ <br> Derate above $25^{\circ} \mathrm{C}$ | PD | 225 | mW |
| Thermal Resistance Junction to Ambient | $\mathrm{R}_{\theta \mathrm{JA}}$ | 556 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction and Storage Temperature | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {Stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

DEVICE MARKING
MMBFJ175LT1 = 6W
ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |

OFF CHARACTERISTICS

| Gate-Source Breakdown Voltage <br> $\left(V_{D S}=0, I_{D}=1.0 \mu \mathrm{~A}\right)$ | $\mathrm{V}_{(\mathrm{BR}) \mathrm{GSS}}$ | 30 | - | V |
| :--- | :---: | :---: | :---: | :---: |
| Gate Reverse Current <br> $\left(V_{\mathrm{DS}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=20 \mathrm{~V}\right)$ | $\mathrm{I}_{\mathrm{GSS}}$ | - | 1.0 | nA |
| Gate-Source Cutoff Voltage <br> $\left(V_{\text {DS }}=15, I_{D}=10 \mathrm{nA}\right)$ | $\mathrm{V}_{\mathrm{GS}}(\mathrm{OFF})$ | 3.0 | 6.0 | V |

ON CHARACTERISTICS

| $\begin{aligned} & \text { Zero-Gate-Voltage Drain Current }{ }^{(2)} \\ & \left(\mathrm{V}_{\mathrm{GS}}=0, \mathrm{~V}_{\mathrm{DS}}=15 \mathrm{~V}\right) \end{aligned}$ |  | IDSS | 7.0 | 60 | mA |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Drain Cutoff Current $\left(\mathrm{V}_{\mathrm{DS}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}\right)$ |  | ID(off) | - | 1.0 | nA |
| Drain Source On Resistance $(\mathrm{ID}=500 \mu \mathrm{~A})$ |  | ${ }^{\text {r DS }}$ (on) | - | 125 | $\Omega$ |
| Input Capacitance | $\begin{gathered} V_{D S}=0, V_{G S}=10 \mathrm{~V} \\ f=1.0 \mathrm{MHz} \end{gathered}$ | Ciss | - | 11 | pF |
| Reverse Transfer Capacitance |  | Crss | - | 5.5 |  |

1. $\mathrm{FR}-5=1.0 \times 0.75 \times 0.062 \mathrm{in}$.
2. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$.

Thermal Clad is a registered trademark of the Berquist Company.
Preferred devices are Motorola recommended choices for future use and best overall value.

## MMBFJ175LT1

## INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

## MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection
interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.


SOT-23

## SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(\max )}$, the maximum rated junction temperature of the die, $R_{\theta J A}$, the thermal resistance from the device junction to ambient, and the operating temperature, $\mathrm{T}_{\mathrm{A}}$. Using the values provided on the data sheet for the SOT-23 package, $P_{D}$ can be calculated as follows:

$$
P_{D}=\frac{T_{J(\max )}-T_{A}}{R_{\theta J A}}
$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature $\mathrm{T}_{\mathrm{A}}$ of $25^{\circ} \mathrm{C}$, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$
\mathrm{PD}=\frac{150^{\circ} \mathrm{C}-25^{\circ} \mathrm{C}}{556^{\circ} \mathrm{C} / \mathrm{W}}=225 \text { milliwatts }
$$

The $556^{\circ} \mathrm{C} / \mathrm{W}$ for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

## SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be $100^{\circ} \mathrm{C}$ or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of $10^{\circ} \mathrm{C}$.
- The soldering temperature and time shall not exceed $260^{\circ} \mathrm{C}$ for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be $5^{\circ} \mathrm{C}$ or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.
* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.


## PACKAGE DIMENSIONS



## MMBFJ175LT1


#### Abstract

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